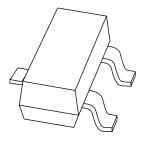
DISCRETE SEMICONDUCTORS

DATA SHEET



BCW31; BCW32; BCW33 NPN general purpose transistors

Product data sheet Supersedes data of 2000 Jul 04 2004 Feb 06



NXP Semiconductors Product data sheet

NPN general purpose transistors

BCW31; BCW32; **BCW33**

FEATURES

- Low current (100 mA)
- Low voltage (32 V).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

NPN transistors in a plastic SOT23 package. PNP complements: BCW29 and BCW30.

MARKING

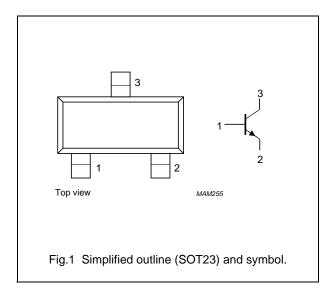
TYPE NUMBER	MARKING CODE(1)
BCW31	D1*
BCW32	D2*
BCW33	D3*

Note

1. * = p : Made in Hong Kong. * = t : Made in Malaysia. * = W : Made in China.

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



ORDERING INFORMATION

TYPE	PACKAGE NAME DESCRIPTION VERSION			
NUMBER				
BCW31	-	plastic surface mounted package; 3 leads	SOT23	
BCW32				
BCW33				

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	-	32	V
V _{CEO}	collector-emitter voltage	open base; I _C = 2 mA	-	32	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		-	100	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

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NPN general purpose transistors

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W	

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 32 V	_	_	100	nA
		$I_E = 0$; $V_{CB} = 32 \text{ V}$; $T_j = 100 ^{\circ}\text{C}$	_	-	10	μΑ
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	_	-	100	nA
h _{FE}	DC current gain	$I_C = 10 \mu A; V_{CE} = 5 V$				
	BCW31		_	190	-	
	BCW32		_	330	_	
	BCW33		_	600	_	
	DC current gain	I _C = 2 mA; V _{CE} = 5 V				
	BCW31		110	_	220	
	BCW32		200	_	450	
	BCW33		420	_	800	
V _{CEsat}	collector-emitter saturation	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	120	250	mV
	voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$	_	210	_	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	750	_	mV
		$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$	_	850	_	mV
V_{BE}	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	550	-	700	mV
C _c	collector capacitance	$I_E = I_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$	_	2.5	_	pF
f _T	transition frequency	I _C = 10 mA; V _{CE} = 5 V; f = 100 MHz	100	_	_	MHz
F	noise figure	$I_{C} = 200 \ \mu A; \ V_{CE} = 5 \ V; \ R_{S} = 2 \ k\Omega; \ f = 1 \ kHz; \ B = 200 \ Hz$	-	_	10	dB

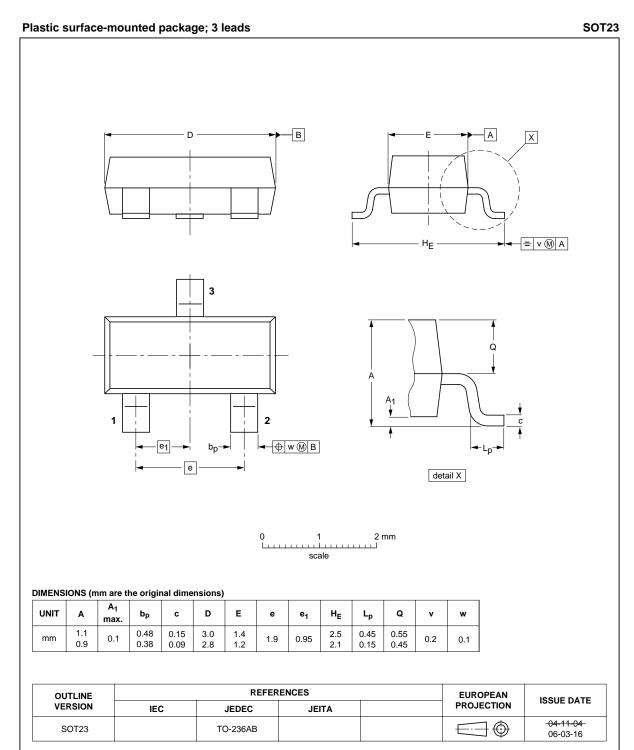
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NXP Semiconductors Product data sheet

NPN general purpose transistors

BCW31; BCW32; BCW33

PACKAGE OUTLINE



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NXP Semiconductors Product data sheet

NPN general purpose transistors

BCW31; BCW32; BCW33

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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